

**VERSION OF CLAIMS WITH MARKINGS TO SHOW CHANGES MADE**

1. (Amended) A method for applying viscous material to at least one semiconductor component, said method comprising:
providing a viscous material pool containing viscous material, said viscous material pool shaped such that an exposed surface of the viscous material is located in a precise location and including at least one upward facing opening, said at least one upward facing opening exposing at least said exposed surface of said viscous material;
aligning at least one semiconductor component over said viscous material pool; and
wetting a specific location of said at least one semiconductor component with said viscous material.
2. (Amended) The method according to claim 1, wherein said providing a viscous material pool containing viscous material comprises providing [a]said viscous material pool containing adhesive or polyimide.
3. (Amended) The method according to claim 2, wherein said providing a viscous material pool containing viscous material comprises providing [a]said viscous material pool containing said adhesive selected from the group consisting of thermoplastics, thermoset resins, flowable pastes, and B-stage adhesive materials.
4. (Amended) The method according to claim 1, wherein said aligning at least one semiconductor component comprises placing at least one of a lead finger, bus bars, and a die attach paddle above said viscous material pool.
5. (Amended) The method according to claim 1, wherein said aligning comprises aligning said at least one semiconductor component above said at least one upward facing opening.

8. (Amended) The method according to claim 1, wherein said wetting [comprising]comprises raising said viscous material pool upward proximate said at least one semiconductor component such that said specific location of said at least one semiconductor component contacts said exposed surface of said viscous material.

11. (Amended) The method according to claim 10, wherein said pumping comprises creating a moving wave of said viscous material traveling across said viscous material pool.

12. (Amended) The method according to claim 1, wherein said wetting comprises applying a layer of said viscous material having a thickness between 0.1 to 15 mils on said specific location of said at least one semiconductor component.

13. (Amended) The method according to claim 1, further comprising coating [said]a surface of the at least one semiconductor component with a surfactant prior to said wetting [said]a specific location of said [surface]at least one semiconductor component with said viscous material.

15. (Amended) The method according to claim 1, further comprising leveling said exposed surface of said viscous material prior to said wetting a specific location of said at least one semiconductor component.

20. (Amended) The method according to claim 1, further comprising controlling the height of said exposed surface of said viscous material using a detection mechanism.

21. (Amended) The method according to claim 20, wherein said controlling the height of said exposed surface of said viscous material comprises:
delivering said viscous material to said viscous material pool;
providing [a]said detection mechanism comprising a transmitter, a receiver, and a control signal;
utilizing said transmitter and said receiver to determine the height of the exposed surface of said viscous material; and
providing said control signal to control said delivery of said viscous material to said viscous material pool.

22. (Amended) The method according to claim 21, wherein said providing said control signal comprises triggering a pump to stop said delivering said viscous material to said viscous material pool when a desired height of said exposed surface is achieved.

24. (Amended) The method according to claim [20]21, wherein said providing a detection mechanism comprises providing a laser transmitter, wherein a light beam from said laser transmitter is altered by the exposed surface and the receiver detects the alteration of said light beam and then generates [a]said control signal.

25. (Amended) The method according to claim 20, wherein said controlling comprises providing a detection mechanism [comprises providing]comprising an ultrasonic transmitter, wherein an ultrasonic sound wave from [the]said ultrasonic transmitter is altered by the exposed surface and the receiver detects the alteration of the ultrasonic sound wave and then generates the control signal.

28. (Amended) The method according to claim 27, further comprising attaching said at least one semiconductor component to a semiconductor die.

29. (Amended) The method according to claim 1, wherein said wetting comprises applying said viscous material to [a precise]said specific location on said at least one semiconductor component under at least a [partially-evacuated]partially evacuated chamber.

30. (Amended) The method according to claim 1, wherein said providing a viscous material pool comprises providing said viscous material pool including an inlet, [and]an outlet and a plate-type reservoir, wherein said at least one upward facing opening exposes said plate-type reservoir and wherein said viscous material flows from said inlet across a plate and into said outlet such that a thin layer of said viscous material is delivered across said plate.

31. (Amended) The method according to claim 1, wherein said providing a viscous material pool comprises providing said viscous material pool including a first chamber, a curved-edge spillway and a spill chamber, wherein said at least one upward facing opening exposes said curved-edge spillway.

33. (Amended) The method according to claim 32, wherein said wetting [comprising]comprises contacting [a]said specific portion of said at least one semiconductor component with the viscous material over the curved-edge spillway.

34. (Amended) A method for applying viscous material to at least one semiconductor component, said method comprising:

providing a viscous material pool including at least one reservoir containing viscous material, said viscous material pool defined by at least one peripheral edge having a height and configured such that an exposed surface of the viscous material is located in a precise location, said viscous material pool including at least one upward facing opening exposing at least said exposed surface of said viscous material, said exposed surface of said viscous material having a height that extends above said height of said at least one peripheral edge;

leveling the exposed surface of said viscous material; and
coating only a specific portion of a surface of at least one semiconductor component with said
viscous material.

35. (Amended) The method according to claim 34, wherein said providing a viscous material pool including at least one reservoir containing viscous material comprises providing [a]said viscous material pool containing adhesive or polyimide.

36. (Amended) The method according to claim 35, wherein said providing a viscous material pool including at least one reservoir containing viscous material comprises providing [a]said viscous material pool containing said adhesive selected from the group consisting of thermoplastics, thermoset resins, flowable pastes, and B-stage adhesive materials.

37. (Amended) The method according to claim 34, wherein said coating only a specific portion of a surface of at least one semiconductor component comprises applying said viscous material to at least one of a lead finger, bus bars, and a die attach paddle.

38. (Amended) The method according to claim 34, wherein said coating only a specific portion of a surface of at least one semiconductor component comprises aligning said at least one semiconductor component over said at least one upward facing opening such that said exposed surface contacts only said specific portion of said surface of said at least one semiconductor component.

39. (Amended) The method according to claim 34, wherein said coating comprises biasing said at least one semiconductor component downward proximate the viscous material in said viscous material pool such that said exposed surface of said viscous material contacts said specific portion of said surface of said at least one semiconductor component.

41. (Amended) The method according to claim 34, wherein said coating [comprising]comprises raising said viscous material pool upward proximate said at least one semiconductor component such that said exposed surface of said viscous material contacts said specific portion of said surface of said at least one semiconductor component.

43. (Amended) The method according to claim 34, wherein said coating comprises pumping said viscous material to a height above said viscous material pool, wherein said height of said viscous material is sufficient to contact only said specific portion of said surface of said at least one semiconductor component.

44. (Amended) The method according to claim 43, wherein said pumping comprises creating a moving wave of said viscous material traveling across said viscous material pool.

45. (Amended) The method according to claim 34, wherein said coating comprises applying a layer of said viscous material having a thickness between 0.1 to 15 mils to said specific [location]portion of said surface of said at least one semiconductor component.

46. (Amended) The method according to claim 34, further comprising coating said surface of the at least one semiconductor component with a surfactant prior to said coating said specific portion of said surface of said at least one semiconductor component with said viscous material.

52. (Amended) The method according to claim 48, further comprising controlling the height of said exposed surface of said viscous material using a detection mechanism.

53. (Amended) The method according to claim 52, wherein said controlling the height of said exposed surface of said viscous material comprises:

delivering said viscous material to said viscous material pool;
providing [a]said detection mechanism comprising a transmitter, a receiver, and a control signal;
utilizing said transmitter and said receiver to determine the height of the exposed surface of said viscous material; and

providing said control signal to control said delivery of said viscous material.

54. (Amended) The method according to claim 53, wherein said providing said control signal comprises triggering a pump to stop said delivering said viscous material to said viscous material pool when a desired height of said viscous material is achieved.

56. (Amended) The method according to claim 52, wherein said controlling comprises providing [a]said detection mechanism [comprises providing]comprising a laser transmitter, wherein a light beam from said laser transmitter is altered by the exposed surface and the receiver detects the alteration of said light beam and then generates [a]said control signal.

57. (Amended) The method according to claim 52, wherein said controlling comprises providing [a]said detection mechanism [comprises providing]comprising an ultrasonic transmitter, wherein an ultrasonic sound wave from the ultrasonic transmitter is altered by the exposed surface and the receiver detects the alteration of said ultrasonic sound wave and then generates the control signal.

59. (Amended) The method according to claim 58, further comprising attaching said at least one semiconductor component to a semiconductor die.

60. (Amended) The method according to claim 34, wherein said coating comprises applying said viscous material to said specific [location]portion of said surface on said at least one semiconductor component under at least a [partially-evacuated]partially evacuated chamber.

61. (Amended) The method according to claim 34, wherein said providing a viscous material pool comprises providing said viscous material pool including an inlet, [and]an outlet and a plate-type reservoir, wherein said at least one upward facing opening exposes said plate-type reservoir and wherein said viscous material flows from said inlet across a plate and into said outlet such that a thin layer of said viscous material is delivered across said plate.

62. (Amended) The method according to claim 34, wherein said providing a viscous material pool comprises providing said viscous material pool including a first chamber, a curved-edge spillway and a spill chamber, wherein said at least one upward facing opening exposes said [curved edge-spillway]curved-edge spillway.

64. (Amended) The method according to claim 63, wherein said [wetting comprising]coating comprises contacting [a]said specific portion of said surface of said at least one semiconductor component with the viscous material over the curved-edge spillway.